

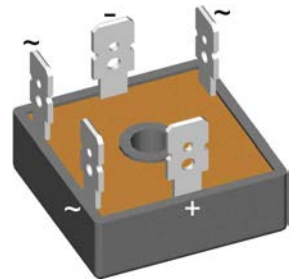
# Standard Rectifier Module

|                         |          |
|-------------------------|----------|
| <b>3~<br/>Rectifier</b> |          |
| $V_{RRM}$               | = 1600 V |
| $I_{DAV}$               | = 20 A   |
| $I_{FSM}$               | = 380 A  |

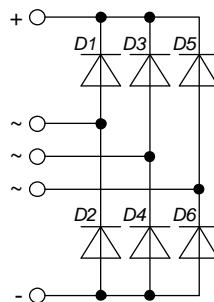
## 3~ Rectifier Bridge

Part number

**VUO25-16N08**



 E72873



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: FO-B

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- ¼" fast-on terminals
- Easy to mount with one screw

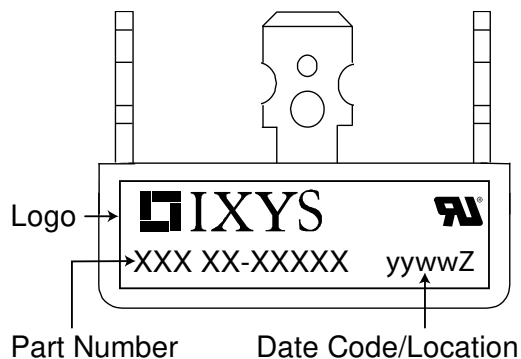
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| Rectifier  |  |                             |                   | Ratings                      |      |                                   |                  |
|------------|--|-----------------------------|-------------------|------------------------------|------|-----------------------------------|------------------|
| Symbol     | Definition                                   | Conditions                  |                   | min.                         | typ. | max.                              | Unit             |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |                             |                   |                              |      | 1700                              | V                |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |                             |                   |                              |      | 1600                              | V                |
| $I_R$      | reverse current                              | $V_R = 1600$ V              |                   | $T_{VJ} = 25^\circ\text{C}$  |      | 40                                | $\mu\text{A}$    |
|            |  | $V_R = 1600$ V              |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 1,5                               | mA               |
| $V_F$      | forward voltage drop                         | $I_F = 10$ A                |                   | $T_{VJ} = 25^\circ\text{C}$  |      | 1,05                              | V                |
|            |  | $I_F = 30$ A                |                   |                              |      | 1,25                              | V                |
|            |  | $I_F = 10$ A                |                   | $T_{VJ} = 125^\circ\text{C}$ |      | 0,94                              | V                |
|            |  | $I_F = 30$ A                |                   |                              |      | 1,21                              | V                |
| $I_{DAV}$  | bridge output current                        | $T_C = 85^\circ\text{C}$    |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 20                                | A                |
|            |  | rectangular                 | $d = \frac{1}{3}$ |                              |      |                                   |                  |
| $V_{FO}$   | threshold voltage                            |                             |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 0,77                              | V                |
| $r_F$      | slope resistance                             |                             |                   |                              |      | 14,2                              | m $\Omega$       |
|            |  |                             |                   |                              |      | } for power loss calculation only |                  |
| $R_{thJC}$ | thermal resistance junction to case          |                             |                   |                              |      | 8                                 | K/W              |
| $R_{thCH}$ | thermal resistance case to heatsink          |                             |                   |                              | 1    |                                   | K/W              |
| $P_{tot}$  | total power dissipation                      |                             |                   | $T_C = 25^\circ\text{C}$     |      | 15                                | W                |
| $I_{FSM}$  | max. forward surge current                   | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 45^\circ\text{C}$  |      | 380                               | A                |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 410                               | A                |
|            |  | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 325                               | A                |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 350                               | A                |
| $I^2t$     | value for fusing                             | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 45^\circ\text{C}$  |      | 720                               | A <sup>2</sup> s |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 700                               | A <sup>2</sup> s |
|            |  | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 530                               | A <sup>2</sup> s |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 510                               | A <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400$ V; $f = 1$ MHz  |                   | $T_{VJ} = 25^\circ\text{C}$  |      | 10                                | pF               |



| Package FO-B  |  | Ratings              |      |      |      |      |
|---------------|--|----------------------|------|------|------|------|
| Symbol        | Definition   | Conditions           | min. | typ. | max. | Unit |
| $I_{RMS}$     | RMS current  | per terminal         |      |      | 100  | A    |
| $T_{VJ}$      | virtual junction temperature                                 |                      | -40  |      | 150  | °C   |
| $T_{op}$      | operation temperature  |                      | -40  |      | 125  | °C   |
| $T_{stg}$     | storage temperature  |                      | -40  |      | 125  | °C   |
| <b>Weight</b> |  |                      |      | 20   |      | g    |
| $M_D$         | mounting torque  |                      | 1,8  |      | 2,2  | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal | 9,0  | 7,0  |      | mm   |
| $d_{Spb/Apb}$ |  | terminal to backside | 10,0 | 10,0 |      | mm   |
| $V_{ISOL}$    | isolation voltage  | t = 1 second         | 3000 |      |      | V    |
|               |  | t = 1 minute         | 2500 |      |      | V    |

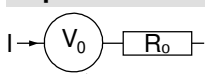


| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VUO25-16NO8     | VUO25-16NO8        | Box           | 50       | 465127   |

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$

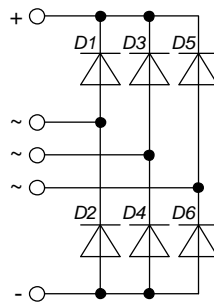
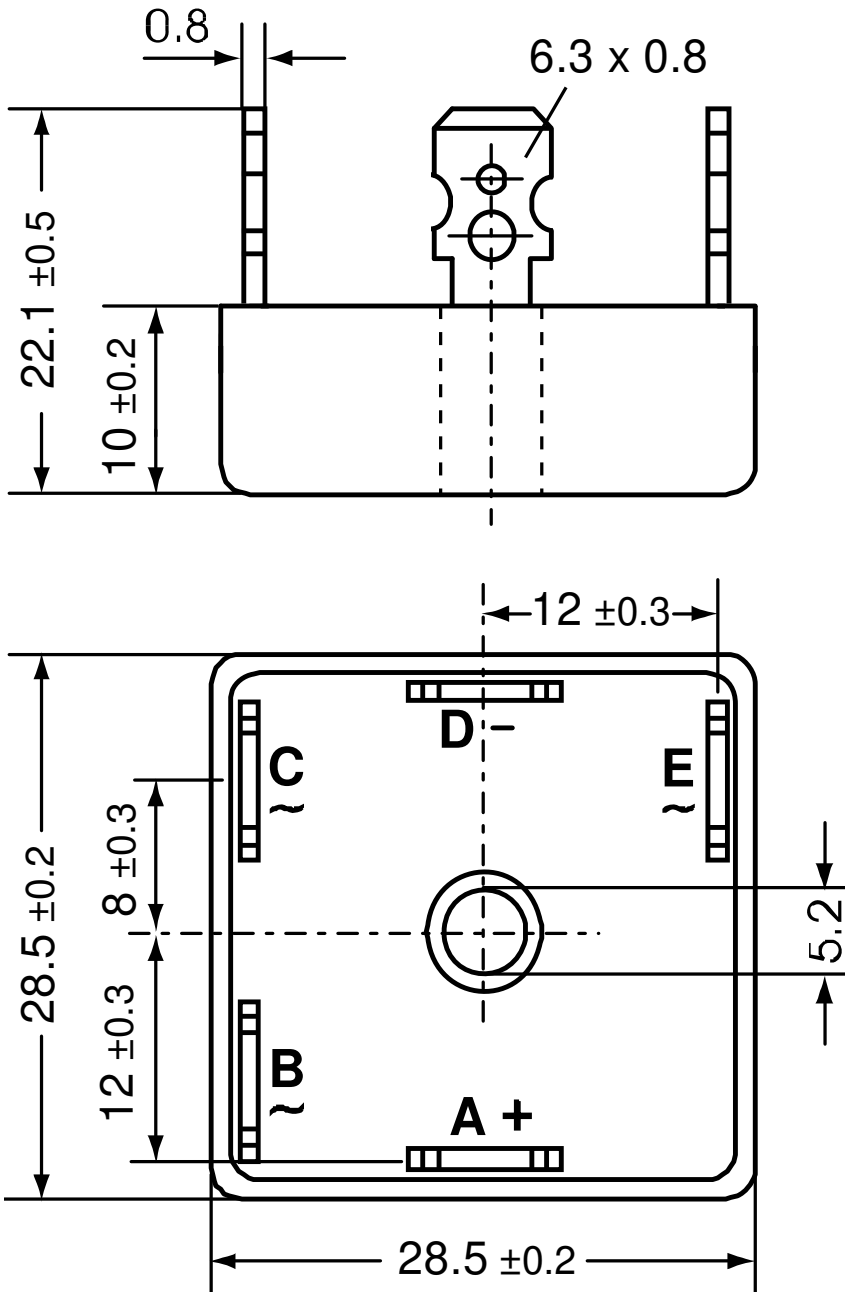


**Rectifier**

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0,77 | V  |
| $R_{0\ max}$ | slope resistance * | 13   | mΩ |



Outlines FO-B





**Rectifier**

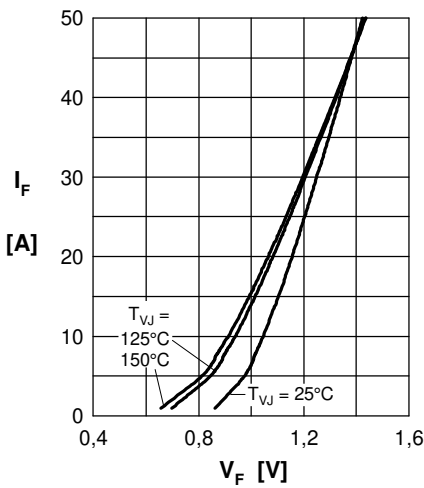


Fig. 1 Forward current vs. voltage drop per diode

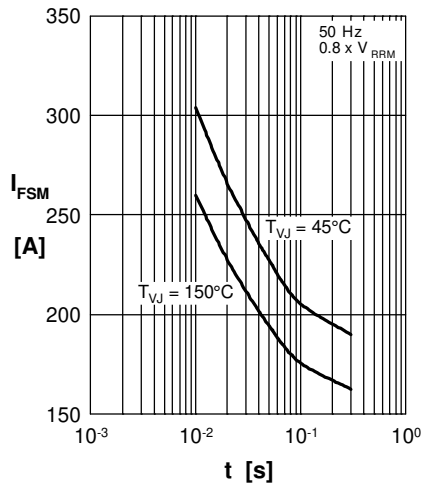


Fig. 2 Surge overload current vs. time per diode

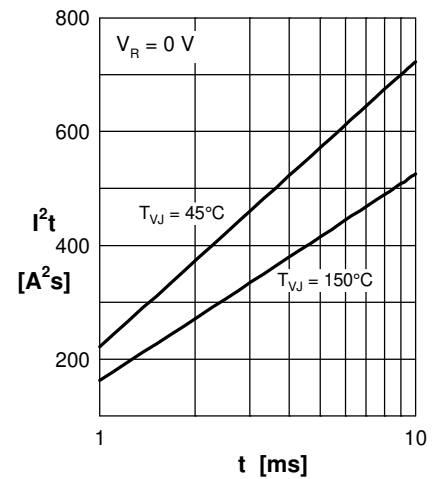


Fig. 3  $I^2t$  vs. time per diode

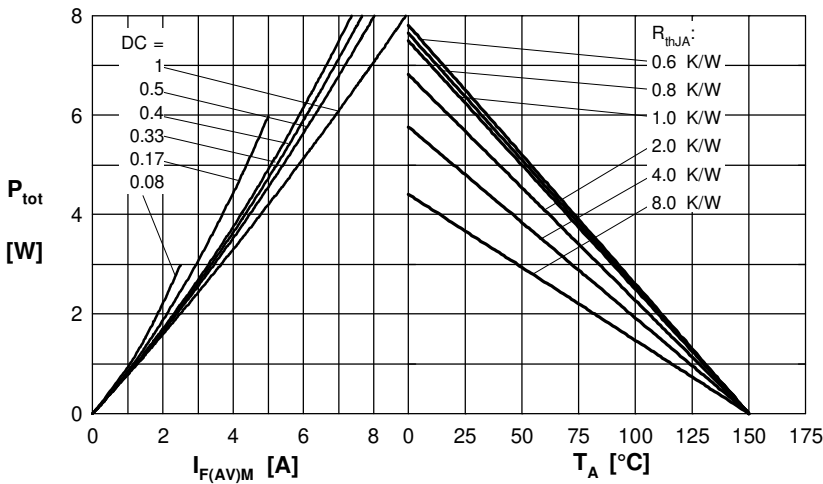


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

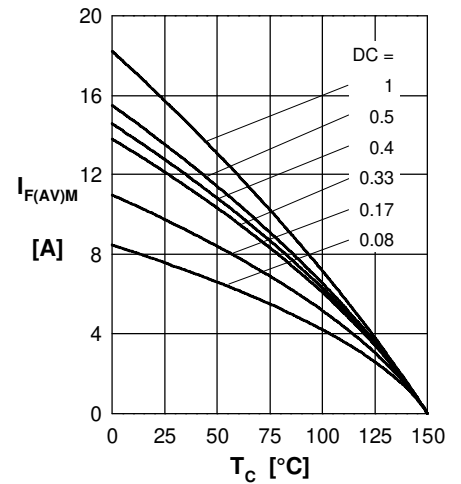


Fig. 5 Max. forward current vs. case temperature per diode

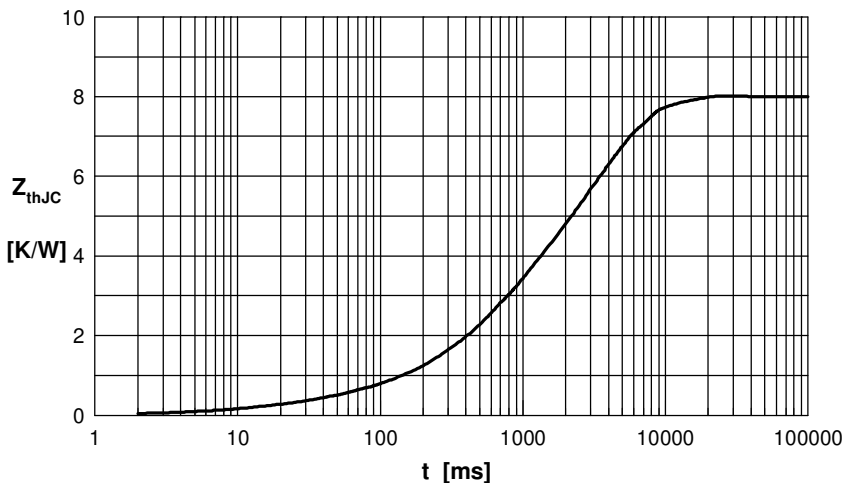


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.040          | 0.005     |
| 2 | 0.250          | 0.030     |
| 3 | 1.810          | 0.500     |
| 4 | 5.900          | 3.200     |